Analog Power

AM4998N

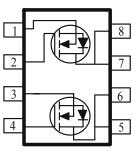
N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	I _D (A)	
30	$32 @ V_{GS} = 4.5V$	6.5	
	$40 @ V_{GS} = 2.5V$	5.8	





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	±12	v	
Continuous Drain Current ^a	$T_A=25^{\circ}C$	I	6.5		
Continuous Drain Current	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1D	±5.3	А	
Pulsed Drain Current ^b		I _{DM}	±50		
Continuous Source Current (Diode Conduction) ^a		I _S	2.3	А	
	$T_A=25^{\circ}C$	D	2.0	W	
Power Dissipation ^a	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1 D	1.3		
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
Maximum Junction-to-Ambient ^a	t <= 10 sec	D	62.5	°C/W		
	Steady-State	R _{0JA}	110	°C/W		

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

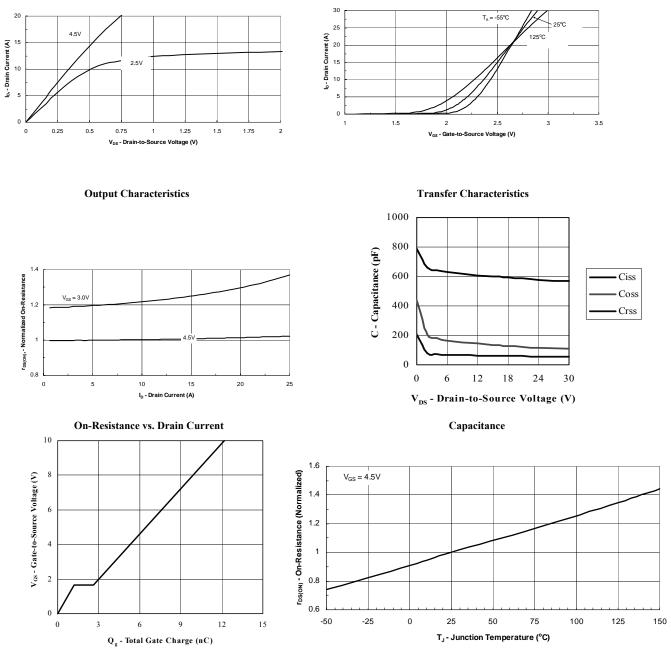
Parameter	Sh al	Test Conditions	Limits			TT:4	
rarameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	0.7				
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			±100	nA	
Zero Gate Voltage Drain Current	Т	$V_{DS} = 24 V, V_{GS} = 0 V$			1	uA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			25	uA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = \pm 12 V$	20			Α	
Durin Granne On Brainford A	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 6.5 \text{ A}$			32	mΩ	
Drain-Source On-Resistance ^A		$V_{GS} = 2.5 \text{ V}, I_D = 5.8 \text{ A}$			40		
Forward Tranconductance ^A	$g_{\rm fs}$	$V_{DS} = 15 \text{ V}, I_D = 6.5 \text{ A}$		40		S	
Diode Forward Voltage	V _{SD}	$I_{\rm S} = 2.3$ A, $V_{\rm GS} = 0$ V		0.7		V	
Dynamic ^b							
Total Gate Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_D = 6.5 \text{ A}$		6.0		nC	
Gate-Source Charge	Q _{gs}			1.0			
Gate-Drain Charge	Q _{gd}			1.5			
Turn-On Delay Time	t _{d(on)}			20			
Rise Time	t _r	V_{DD} = 25 V, R_L = 25 Ω , ID = 1 A, V_{GEN} = 10 V		9		nS	
Turn-Off Delay Time	t _{d(off)}			70			
Fall-Time	t _f			20		1	

Notes

- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

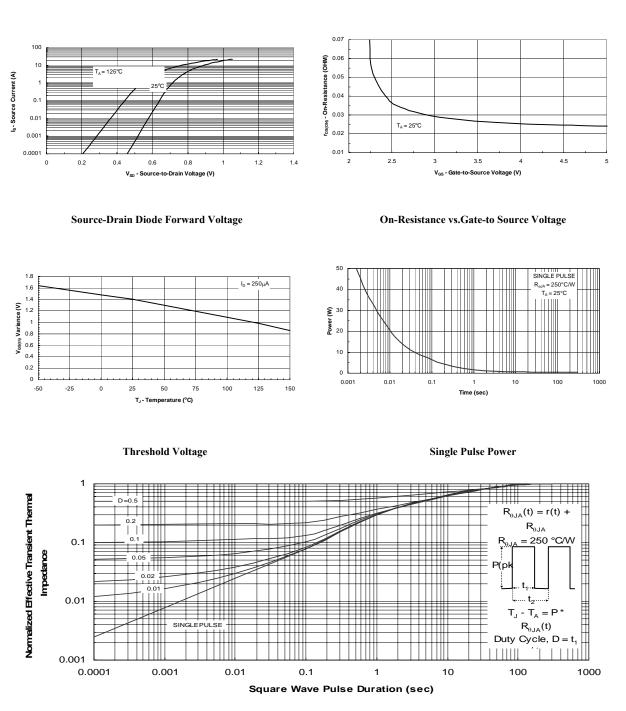
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Typical Electrical Characteristics



Gate Charge

On-Resistance vs. Junction Temperature



Typical Electrical Characteristics (N-Channel)

Normalized Thermal Transient Impedance, Junction-to-Ambient

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